Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Ceramic and metal

Overall Length:

0.200 inches

Overall Height:

0.103 inches

Overall Width:

0.103 inches

Mounting Method:

Press fit

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

150.0 working peak reverse voltage

Current Rating Per Characteristic:

35.00 amperes forward current, average preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Test Data Document:

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 case

Specification Data:

81349-mil-prf-19500/477 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.